

Ultrafast recovery diode

Main product characteristics

$I_{F(AV)}$	12 A
V_{RRM}	200 V
$T_j (max)$	175° C
$V_F (typ)$	0.82 V
$t_{rr} (typ)$	18 ns

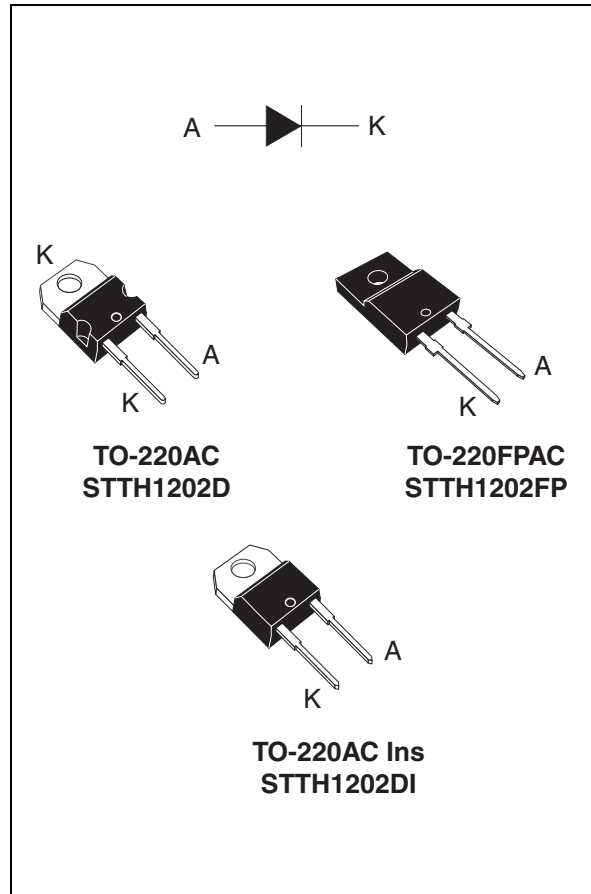
Features and benefits

- Very low conduction losses
- Negligible switching losses
- Low forward and reverse recovery time
- High junction temperature
- Insulated packages
 - TO-220FPAC
Electrical insulation 1500 V_{RMS}
 - TO-220AC Ins
Electrical insulation 2500 V_{RMS}

Description

The STTH1202 uses ST's new 200V planar Pt doping technology, and is specially suited for switching mode base drive and transistor circuits.

Packaged in TO-220AC, TO-220FPAC, and TO-220AC Ins, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection.



Order codes

Part Number	Marking
STTH1202D	STTH1202
STTH1202FP	STTH1202
STTH1202DI	STTH1202DI

1 Characteristics

Table 1. Absolute ratings (limiting values at $T_j = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			200	V
V _{RSM}	Non repetitive peak reverse voltage			200	
I _{F(RMS)}	RMS forward current			30	A
I _{F(AV)}	Average forward current, δ = 0.5	TO-220AC	T _c = 140° C	12	A
		TO-220AC Ins	T _c = 130° C		
		TO-220FPAC	T _c = 105° C		
I _{FRM}	Repetitive peak forward current	t _p = 10 μs F = 5 kHz square		130	A
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms Sinusoidal		100	A
T _{stg}	Storage temperature range			-65 to + 175	° C
T _j	Maximum operating junction temperature			175	° C

Table 2. Thermal parameters

Symbol	Parameter			Value	Unit
$R_{th(j-c)}$	Junction to case	TO-220AC		2.5	$^\circ\text{C/W}$
		TO-220AC Ins		3	
		TO-220FPAC		5	

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Typ	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			10	μA
		$T_j = 125^\circ\text{C}$			10	100	
$V_F^{(2)}$	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 12\ \text{A}$		1.0	1.10	V
		$T_j = 150^\circ\text{C}$			0.82	0.95	
		$T_j = 25^\circ\text{C}$	$I_F = 15\ \text{A}$			1.15	
		$T_j = 125^\circ\text{C}$			0.91	1.05	
		$T_j = 150^\circ\text{C}$			0.87	1.0	

1. Pulse test: $t_p = 5\ \text{ms}$, $\delta < 2\%$

2. Pulse test: $t_p = 380\ \mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.77 \times I_{F(AV)} + 0.015 \times I_{F(RMS)}^2$$

Table 4. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Typ	Max.	Unit
t_{rr}	Reverse recovery time	$I_F = 1\text{ A}$, $di_F/dt = -50\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$, $T_j = 25^\circ\text{C}$		28	35	ns
		$I_F = 1\text{ A}$, $di_F/dt = -100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$, $T_j = 25^\circ\text{C}$		18	24	
I_{RM}	Reverse recovery current	$I_F = 12\text{ A}$, $di_F/dt = -200\text{ A}/\mu\text{s}$, $V_R = 160\text{ V}$, $T_j = 125^\circ\text{C}$		5.8	7.5	A
t_{fr}	Forward recovery time	$I_F = 12\text{ A}$, $di_F/dt = 100\text{ A}/\mu\text{s}$, $V_{FR} = 1.1 \times V_{Fmax}$, $T_j = 25^\circ\text{C}$		110		ns
V_{FP}	Forward recovery voltage	$I_F = 12\text{ A}$, $di_F/dt = 100\text{ A}/\mu\text{s}$, $T_j = 25^\circ\text{C}$		2		V

Figure 1. Peak current versus duty cycle

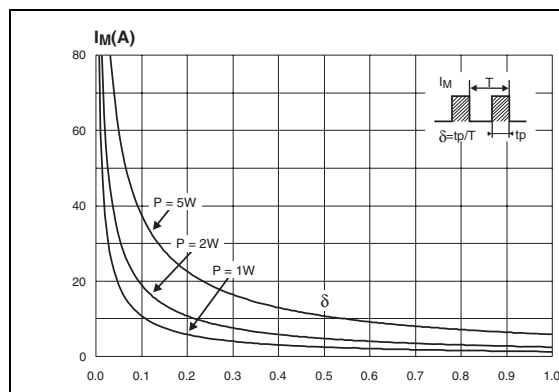


Figure 3. Relative variation of thermal impedance, junction to case, versus pulse duration (TO-220AC, TO-220AC Ins)

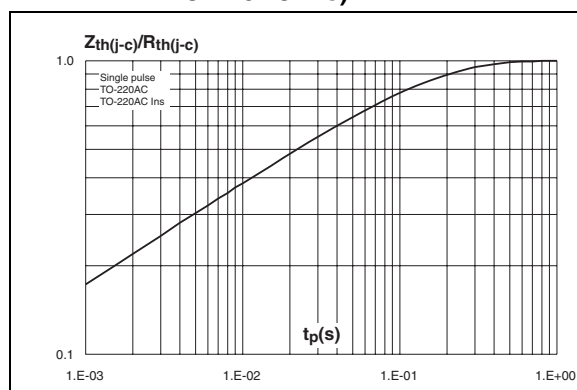


Figure 2. Forward voltage drop versus forward current (typical values)

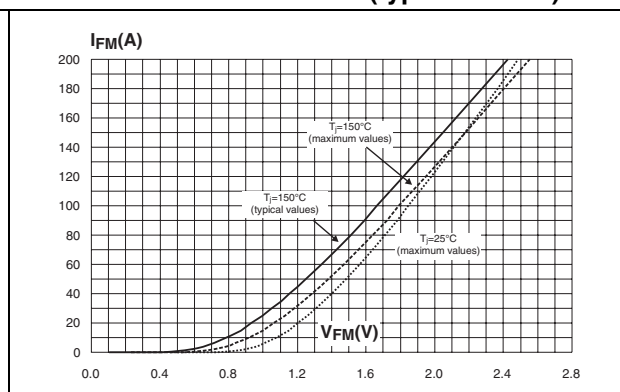


Figure 4. Relative variation of thermal impedance, junction to case, versus pulse duration (TO-220FPAC)

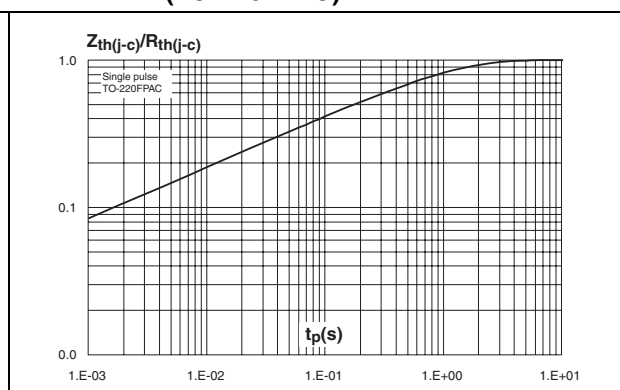


Figure 5. Junction capacitance versus reverse applied voltage (typical values)

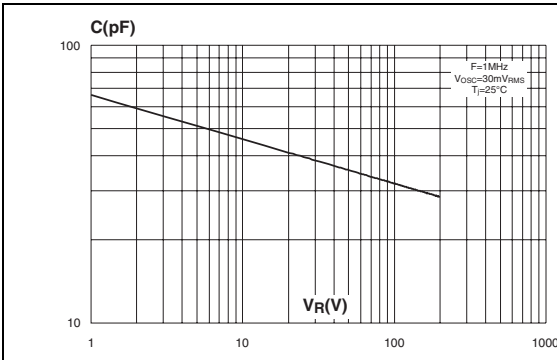


Figure 6. Reverse recovery charges versus di_F/dt (typical values)

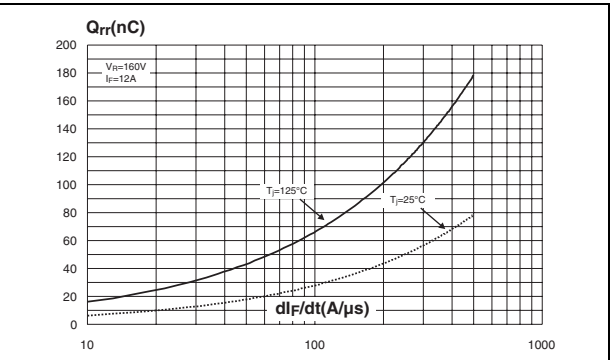


Figure 7. Reverse recovery time versus di_F/dt (typical values)

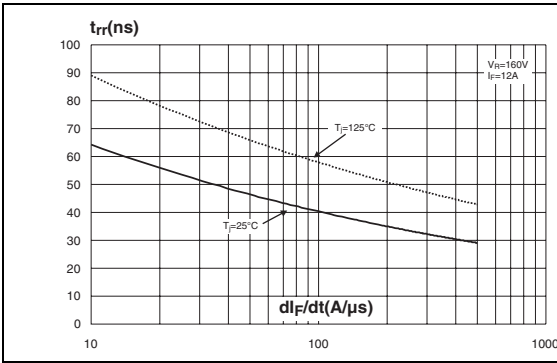


Figure 8. Peak reverse recovery current versus di_F/dt (typical values)

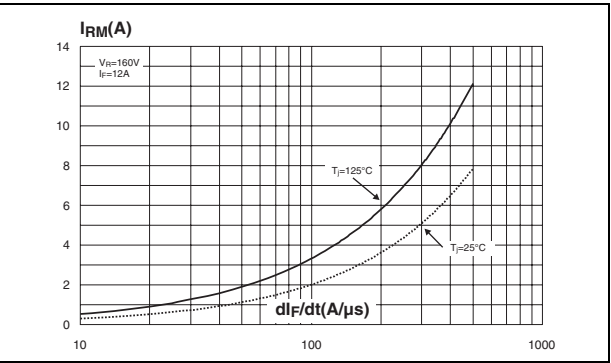
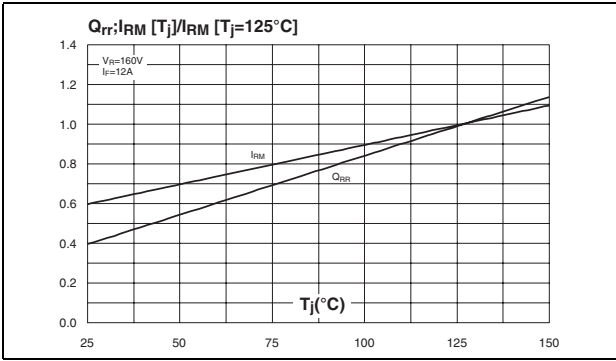
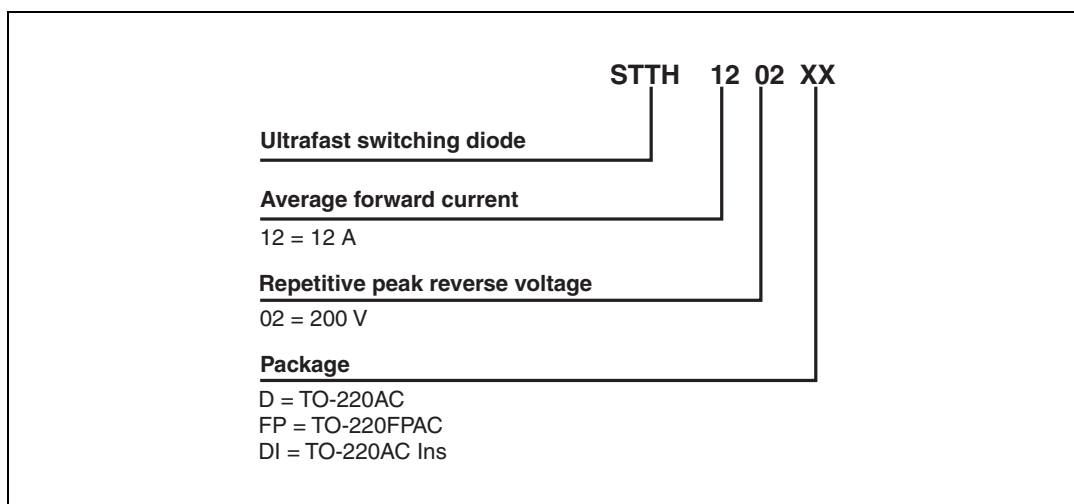


Figure 9. Dynamic parameters versus junction temperature



2 Ordering information scheme



3 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 Nm
- Maximum torque value: 0.7 Nm

Table 5. T0-220AC dimensions

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
H2	10.00	10.40	0.393	0.409
L2	16.40 typ.		0.645 typ.	
L4	13.00	14.00	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam. I	3.75	3.85	0.147	0.151

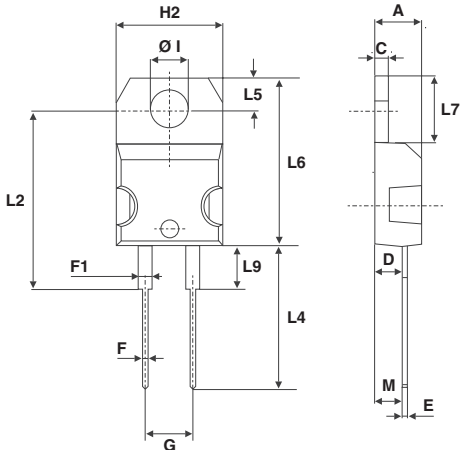


Table 6. T0-220FPAC dimensions

REF	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	2.5	2.7	0.098	0.106
D	2.5	2.75	0.098	0.108
E	0.45	0.70	0.018	0.027
F	0.75	1	0.030	0.039
F1	1.15	1.70	0.045	0.067
G	4.95	5.20	0.195	0.205
G1	2.4	2.7	0.094	0.106
H	10	10.4	0.393	0.409
L2	16 Typ.		0.63 Typ.	
L3	28.6	30.6	1.126	1.205
L4	9.8	10.6	0.386	0.417
L5	2.9	3.6	0.114	0.142
L6	15.9	16.4	0.626	0.646
L7	9.00	9.30	0.354	0.366
Dia.	3.00	3.20	0.118	0.126

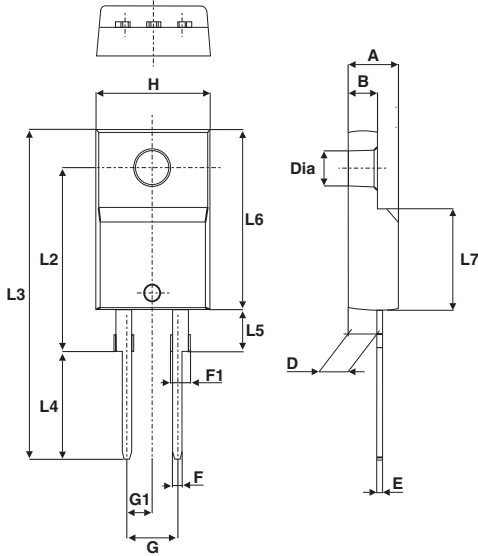


Table 7. TO-220AC Ins. dimensions

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	4.80		5.40	0.189		0.212
F	6.20		6.60	0.244		0.259
ØI	3.75		3.85	0.147		0.151
l4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
l2	1.14		1.70	0.044		0.066
M		2.60			0.102	

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

4 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
STTH1202D	STTH1202	TO-220AC	1.86 g	50	Tube
STTH1202FP	STTH1202	TO-220FPAC	1.64 g	50	Tube
STTH1202DI	STTH1202DI	TO-220AC Ins	2.3 g	50	Tube

5 Revision history

Date	Revision	Description of Changes
01-Mar-2007	1	First issue.

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9